Schottky Barrier Diode

Features

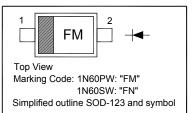
- High reliability
- Low forward voltage and reverse current

Applications

- For electronic calculator, etc.
- · Low current rectification and high speed switching

PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode



Absolute Maximum Ratings (T_a = 25°C)

Parameter	Symbol	Value	Unit
Peak Reverse Voltage	V_{RM}	45	٧
Reverse Voltage	V_R	10	V
Peak Forward Current	I _{FM}	150	mA
Average Rectified Output Current	Io	50	mA
Surge Forward Current	I _{surge}	500	mA
Junction Temperature	T _j	125	°C
Storage Temperature Range	T_{stg}	-55 to +125	°C

Characteristics ($T_a = 25$ °C)

Parameter	Symbol	Min.	Max.	Unit
Reverse Voltage at I _R = 100 µA	V_{R}	45	-	V
Forward Current at $V_F = 1 \text{ V}$	I _F	4	-	mA
Reverse Current 1N60PW 1N60SW	I _R	-	50 100	μΑ
Rectification efficiency at Vi = 2 Vrms, R = 5 K Ω , C = 20 pF, f = 40 MHz	η	55	-	%

Pair Δ I_F \leq 6 mA at 1V, Δ I_R \leq 20 μ A at 10 V



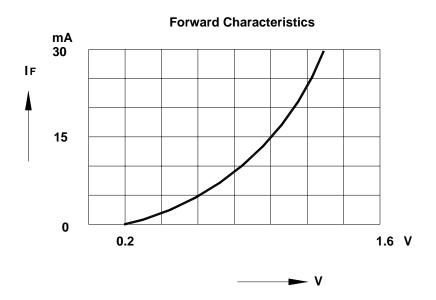


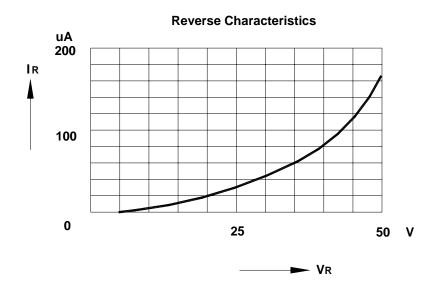


















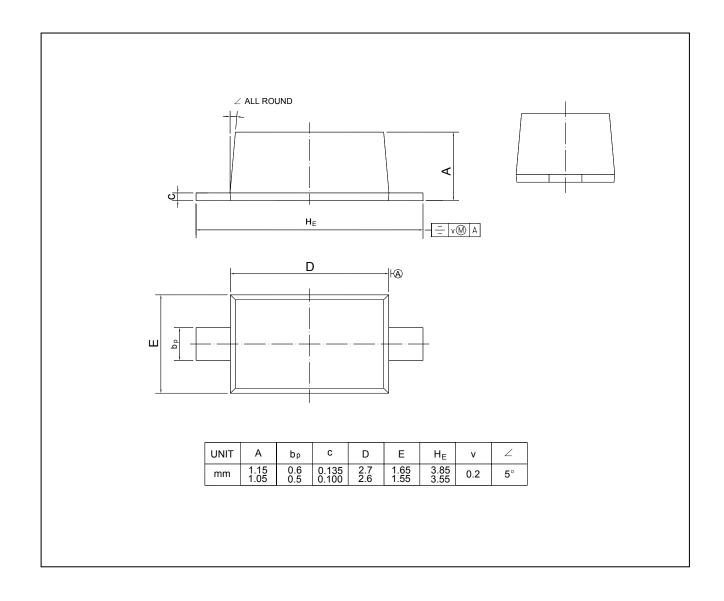




PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD-123













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